Unit: mm

1.6 MAX.

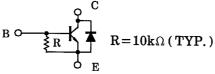
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

# **RN5006**

Motor Drive Circuit Applications **Power Amplifier Applications Power Switching Applications** 

- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Small flat package
- $PC = 1 \sim 2W$  (mounted on ceramic substrate)
- Complementary to RN6006

## **Equivalent Circuit**



#### **TOSHIBA** Weight: 0.05g (typ.)

PW-MINI

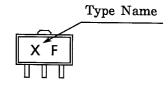
JEDEC

**JEITA** 

3. EMITTER

 $1.5\pm0.1$ 

### Marking



 $1.5 \pm 0.1$ 

COLLECTOR (HEAT SINK)

SC-62

2-5K1A

#### **Maximum Ratings (Ta = 25°C)**

Characteristic		Symbol	Rating	Unit	
Collector-base voltage		$V_{CBO}$	10	V	
Collector-emitter voltage		$V_{CEO}$	10	V	
Emitter-base voltage		V <sub>EBO</sub>	6	V	
Collector current	DC	Ic	2	А	
	Pulse (Note1)	I <sub>CP</sub>	4		
Base current		ΙΒ	0.4	Α	
Collector power dissipation		PC	500	mW	
Collector power dissipation		P <sub>C</sub> *	1000	mW	
Junction temperature		Tj	150	°C	
Storage temperature range		T <sub>stg</sub>	-55~150	°C	

1

Note: Pulse width  $\leq 10$ ms, duty cycle  $\leq 30$  %

<sup>\* :</sup> Mounterd on ceramic substrate  $(250 \text{mm}^2 \times 0.8 \text{t})$ 

# Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Collector cut-offcurrent	I <sub>CBO</sub>	_	V <sub>CB</sub> = 10V, I <sub>E</sub> = 0	_	_	0.1	μΑ
Emitter cut-off current	I <sub>EBO</sub>	_	V <sub>EB</sub> = 6V, I <sub>C</sub> = 0	0.462	0.60	0.857	mA
Collector-emitter breakdown voltage	V <sub>(BR)CES</sub>	_	I <sub>C</sub> = 1mA	10	_	-	V
DC current gain	h <sub>FE (1)</sub>	_	V <sub>CE</sub> = 1V, I <sub>C</sub> = 0.5A	160	_	600	_
	h <sub>FE (2)</sub>		V <sub>CE</sub> = 1V, I <sub>C</sub> = 4.0A	60	_	_	
Collector-emitter saturation voltage	V <sub>CE (sat)</sub>	_	I <sub>C</sub> = 2A, I <sub>B</sub> = 0.05A	_	_	0.5	V
Transition frequency	f <sub>T</sub>	_	V <sub>CE</sub> = 1V, I <sub>C</sub> = 0.5A	_	140	-	MHz
Collector output capacitance	C <sub>ob</sub>	_	V <sub>CB</sub> = 10V, I <sub>E</sub> = 0, f = 1 MHz	_	30	_	pF
Resistor	R	_	_	7	10	13	kΩ

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